# Switching (-20V, -2.5A)

# RTR025P02

#### Features

- 1) Low On-resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small and Surface Mount Package (TSMT3).

### Application

Power switching, DC / DC converter.

### ●Structure

Silicon P-channel MOS FET

# Packaging specifications

	Package	Taping	
Type	Code	TL	
	Basic ordering unit (pieces)	3000	
RTR025P02		0	

# ● Absolute maximum ratings (Ta=25°C)

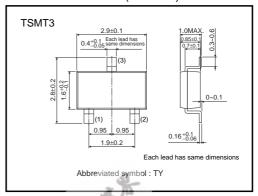
Parameter		Symbol	Limits	Unit	
Drain-source voltage		V <sub>DSS</sub>	-20	V	
Gate-source voltage		Vgss	±12	V	
Drain current	Continuous	ID	±2.5	Α	
	Pulsed	IDP *1	±10	Α	
Source current (Body diode)	Continuous	Is	-0.8	Α	
	Pulsed	Isp *1	-3.2	Α	
Total power dissipation		P <sub>D</sub> *2	1.0	W	
Channel temperature		Tch	150	°C	
Range of Storage temperature		Tstg	-55 to +150	°C	

<sup>\*1</sup> Pw≤10μs, Duty cycle≤1% \*2 Mounted on a ceramic board

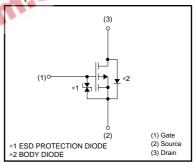
# ●Thermal resistance (Ta=25°C)

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Parameter	Symbol	Limits	Unit
Channel to ambient	Rth (ch-A)	125	°C / W

# ●External dimensions (Unit : mm)



# Equivalent circuit



# ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	Igss	_	-	±10	μΑ	Vgs=±12V, Vps=0V
Drain-source breakdown voltage	V <sub>(BR) DSS</sub>	-20	_	_	٧	I <sub>D</sub> = -1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	I <sub>DSS</sub>	-	_	-1	μΑ	V <sub>DS</sub> = -20V, V <sub>GS</sub> =0V
Gate threshold voltage	V <sub>GS (th)</sub>	-0.7	_	-2.0	V	$V_{DS} = -10V, I_{D} = -1mA$
Static drain-source on-state resistance	R <sub>DS (on)</sub> *	-	70	95	mΩ	I <sub>D</sub> = -2.5A, V <sub>GS</sub> = -4.5V
		-	75	105	mΩ	I <sub>D</sub> = -2.5A, V <sub>GS</sub> = -4.0V
		-	115	160	$m\Omega$	I <sub>D</sub> = -1.25A, V <sub>G</sub> S= -2.5V
Forward transfer admittance	Y <sub>fs</sub>   *	2.3	_	_	S	$V_{DS} = -10V$ , $I_{D} = -1.2A$
Input capacitance	Ciss	_	630	_	pF	V <sub>DS</sub> = -10V
Output capacitance	Coss	_	110	_	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	Crss	-	75	_	pF	f=1MHz
Turn-on delay time	<b>t</b> d (on) *	-	12	_	ns	I <sub>D</sub> = -1.25A
Rise time	tr *	_	18	_	ns	V <sub>DD</sub> ≒ −15V
Turn-off delay time	t <sub>d (off)</sub> *	-	50	_	ns	V <sub>GS</sub> = -4.5V R <sub>L</sub> =12Ω
Fall time	t <sub>f</sub> *	_	20	_	ns	Rgs=10Ω
Total gate charge	Qg	_	7	_	nC	V <sub>DD</sub> ≒−15V
Gate-source charge	Qgs	_	1.5	_	nC	Vgs=-4.5V
Gate-drain charge	Qgd	_	2.0	_	nC	ID=-2.5A
*Pulsed	, Z /là					
	Body diode characteristics (source-drain characteristics)					
Forward voltage	V <sub>SD</sub>		_	-1.2	V	I <sub>S</sub> = -0.8A, V <sub>G</sub> S=0V
in a com.						



# Electrical characteristic curves

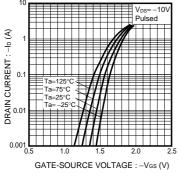


Fig.1 Typical Transfer Characteristics

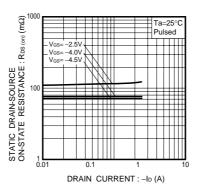


Fig.2 Static Drain-Source On-State Resistance vs. Drain Current

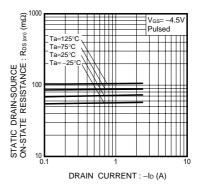


Fig.3 Static Drain-Source On-State Resistance vs. Drain Current

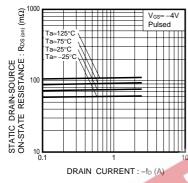


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current

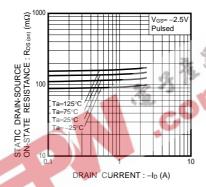


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current

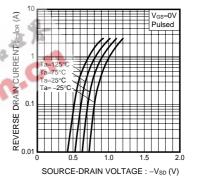


Fig.6 Reverse Drain Current vs.Source-Drain Voltage

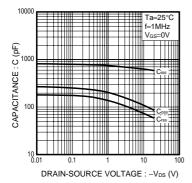


Fig.7 Typical Capacitance vs. Drain-Source Voltage

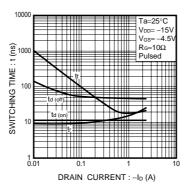


Fig.8 Switching Characteristics

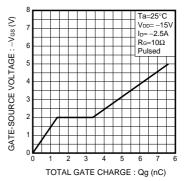


Fig.9 Dynamic Input Characteristics

# ●Measurement circuits

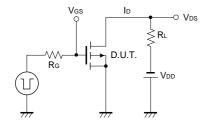


Fig.10 Switching Time Test Circuit

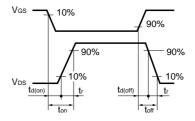


Fig.11 Switching Time Waveforms

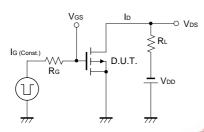


Fig.12 Gate Charge Test Circuit

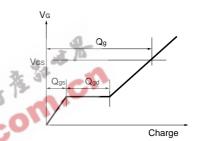


Fig.13 Gate Charge Waveform

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